

# RGW60TS65DHR

650V 30A Field Stop Trench IGBT

V <sub>CES</sub>	650V
Ι <sub>C (100°C)</sub>	30A
V <sub>CE(sat) (Typ.)</sub>	1.5V
P <sub>D</sub>	178W

#### Features

- 1) AEC-Q101 Qualified
- 2) Low Collector Emitter Saturation Voltage
- 3) Low Switching Loss & Soft Switching
- 4) Built in Very Fast & Soft Recovery FRD
- 5) Pb free Lead Plating ; RoHS Compliant

#### Application

Automotive

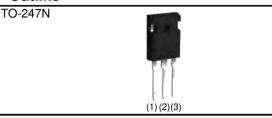
On & Off Board Chargers

DC-DC Converters

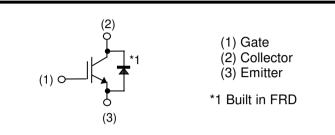
PFC

Industrial Inverter

#### Outline



#### Inner Circuit



#### Packaging Specifications

	Packaging	Tube
	Reel Size (mm)	-
Tuno	Tape Width (mm)	-
Туре	Basic Ordering Unit (pcs)	450
	Packing Code	C11
	Marking	RGW60TS65D

#### •Absolute Maximum Ratings (at T<sub>C</sub> = 25°C unless otherwise specified)

Parameter		Symbol	Value	Unit
Collector - Emitter Voltage		V <sub>CES</sub>	650	V
Gate - Emitter Voltage		V <sub>GES</sub>	±30	V
Collector Current	$T_{\rm C} = 25^{\circ}{\rm C}$	Ι <sub>C</sub>	64	Α
Collector Current	$T_{\rm C} = 100^{\circ}{\rm C}$	Ι <sub>C</sub>	39	Α
Pulsed Collector Current		I <sub>CP</sub> *1	120	Α
Diode Forward Current	$T_{\rm C} = 25^{\circ}{\rm C}$	I <sub>F</sub>	41	Α
	$T_{C} = 100^{\circ}C$	I <sub>F</sub>	25	Α
Diode Pulsed Forward Current		I <sub>FP</sub> <sup>*1</sup>	120	Α
Dower Dissignation	$T_{\rm C} = 25^{\circ}{\rm C}$	P <sub>D</sub>	178	W
Power Dissipation	$T_{\rm C} = 100^{\circ}{\rm C}$	P <sub>D</sub>	89	W
Operating Junction Temperature		T <sub>j</sub>	-40 to +175	°C
Storage Temperature		T <sub>stg</sub>	-55 to +175	°C

\*1 Pulse width limited by  $T_{jmax}$ .

#### •Thermal Resistance

Baramatar	Symbol	Values			Unit
Parameter	Symbol	Min.	Тур.	Max.	Unit
Thermal Resistance IGBT Junction - Case	$R_{\theta(j\text{-}c)}$	-	-	0.84	°C/W
Thermal Resistance Diode Junction - Case	$R_{\theta(j\text{-}c)}$	-	-	1.62	°C/W

### ●IGBT Electrical Characteristics (at T<sub>j</sub> = 25°C unless otherwise specified)

Parameter	Symbol Conditions		Values			Unit
	Symbol	Conditions	Min.	Тур.	Max.	Unit
Collector - Emitter Breakdown Voltage	BV <sub>CES</sub>	$I_{\rm C}$ = 10µA, $V_{\rm GE}$ = 0V	650	-	_	V
Collector Cut - off Current	I <sub>CES</sub>	$V_{CE} = 650V, V_{GE} = 0V$	-	-	10	μA
Gate - Emitter Leakage Current	I <sub>GES</sub>	$V_{GE} = \pm 30V, V_{CE} = 0V$	-	-	±200	nA
Gate - Emitter Threshold Voltage	$V_{\text{GE(th)}}$	$V_{CE} = 5V, I_{C} = 20.0 \text{mA}$	5.0	6.0	7.0	V
Collector - Emitter Saturation Voltage	V <sub>CE(sat)</sub>	$I_{C} = 30A, V_{GE} = 15V,$ $T_{j} = 25^{\circ}C$ $T_{j} = 175^{\circ}C$	-	1.5 1.85	1.9 -	V

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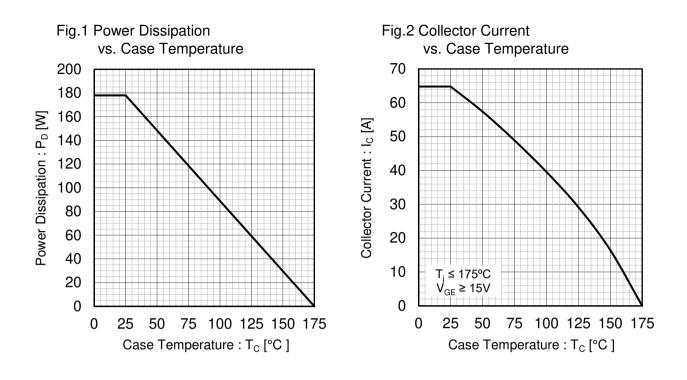
# •IGBT Electrical Characteristics (at $T_j = 25^{\circ}C$ unless otherwise specified)

Parameter	Symbol Conditions		Unit			
		Conditions	Min.	Тур.	Max.	Unit
Input Capacitance	C <sub>ies</sub>	$V_{CE} = 30V,$	-	2530	-	
Output Capacitance	C <sub>oes</sub>	$V_{GE} = 0V,$	-	65	-	pF
Reverse transfer Capacitance	C <sub>res</sub>	f = 1MHz	-	46	-	
Total Gate Charge	Qg	V <sub>CE</sub> = 400V,	-	84	-	
Gate - Emitter Charge	Q <sub>ge</sub>	I <sub>C</sub> = 30A,	-	17	-	nC
Gate - Collector Charge	Q <sub>gc</sub>	V <sub>GE</sub> = 15V	-	31	-	
Turn - on Delay Time	t <sub>d(on)</sub>		-	36	-	
Rise Time	t <sub>r</sub>	$I_{C} = 15A, V_{CC} = 400V,$ $V_{GE} = 15V, R_{G} = 10\Omega,$	-	9	-	ns
Turn - off Delay Time	t <sub>d(off)</sub>	$T_i = 25^{\circ}C$	-	107	-	
Fall Time	t <sub>f</sub>	Inductive Load	-	55	-	
Turn - on Switching Loss	E <sub>on</sub>	*E <sub>on</sub> include diode reverse recovery	-	0.16	-	ml
Turn - off Switching Loss	E <sub>off</sub>	,	-	0.24	-	mJ
Turn - on Delay Time	t <sub>d(on)</sub>		-	34	-	
Rise Time	t <sub>r</sub>	$I_{C} = 15A, V_{CC} = 400V,$ $V_{GF} = 15V, R_{G} = 10\Omega,$	-	10	-	20
Turn - off Delay Time	t <sub>d(off)</sub>	$T_i = 175^{\circ}C$	-	139	-	ns
Fall Time	t <sub>f</sub>	Inductive Load	-	76	-	
Turn - on Switching Loss	E <sub>on</sub>	*E <sub>on</sub> include diode reverse recovery	-	0.17	-	mJ
Turn - off Switching Loss	E <sub>off</sub>		-	0.33	-	IIIJ
Reverse Bias Safe Operating Area	RBSOA	$\begin{split} I_{C} &= 120 \text{A}, \ V_{CC} = 520 \text{V}, \\ V_{P} &= 650 \text{V}, \ V_{GE} = 15 \text{V}, \\ R_{G} &= 100 \Omega, \ T_{j} = 175^{\circ} \text{C} \end{split}$	FU	ILL SQUA	RE	-

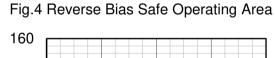
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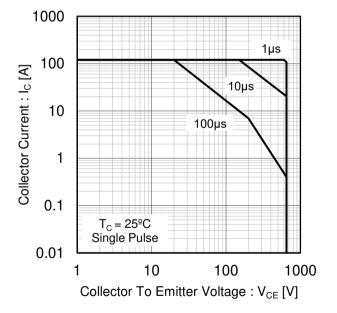
# •FRD Electrical Characteristics (at $T_j = 25^{\circ}C$ unless otherwise specified)

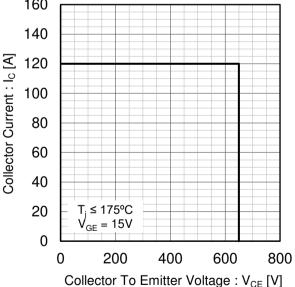
Parameter	Symbol	Conditions	Values			Lloit
	Symbol		Min.	Тур.	Max.	Unit
		I <sub>F</sub> = 20A,				
Diode Forward Voltage	$V_{F}$	$T_j = 25^{\circ}C$	-	1.45	1.9	V
		$T_j = 175^{\circ}C$	-	1.55	-	
Diode Reverse Recovery Time	t <sub>rr</sub>		-	87	-	ns
Diode Peak Reverse Recovery Current	I <sub>rr</sub>	I <sub>F</sub> = 15A, V <sub>CC</sub> = 400V,	-	5.7	-	A
Diode Reverse Recovery Charge	Q <sub>rr</sub>	di <sub>F</sub> /dt = 200A/µs, T <sub>j</sub> = 25°C	-	0.27	-	μC
Diode Reverse Recovery Energy	E <sub>rr</sub>		-	11.0	-	μJ
Diode Reverse Recovery Time	t <sub>rr</sub>	I <sub>F</sub> = 15A, V <sub>CC</sub> = 400V, di <sub>F</sub> /dt = 200A/µs, T <sub>j</sub> = 175°C	-	122	-	ns
Diode Peak Reverse Recovery Current	I <sub>rr</sub>		-	6.9	-	A
Diode Reverse Recovery Charge	Q <sub>rr</sub>		-	0.51	-	μC
Diode Reverse Recovery Energy	E <sub>rr</sub>		-	26.5	_	μJ

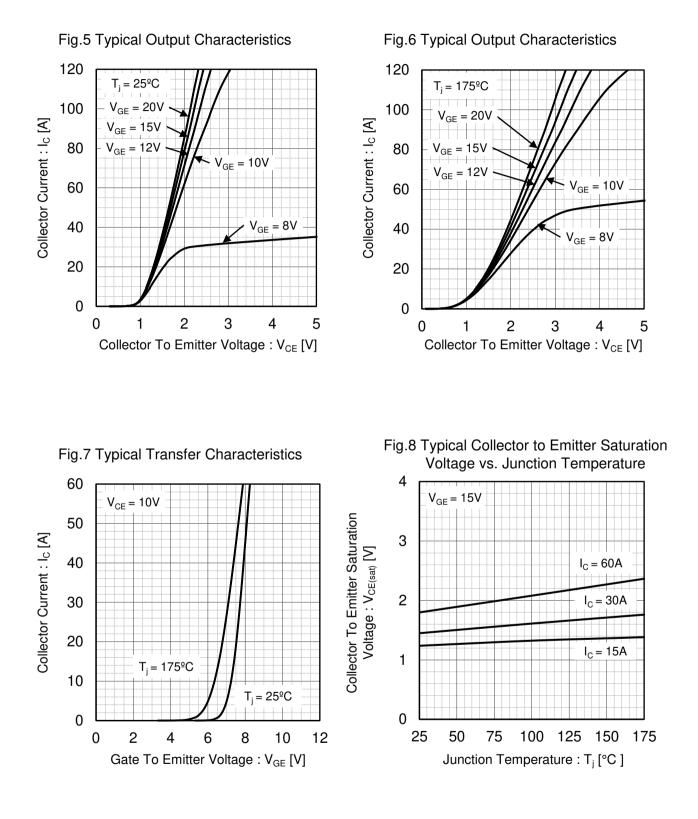


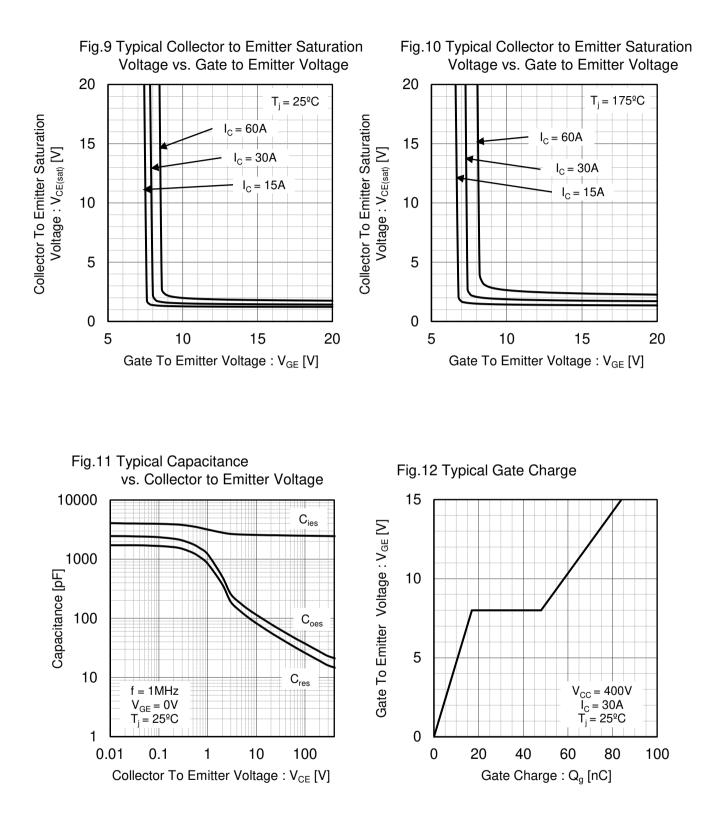
## Fig.3 Forward Bias Safe Operating Area

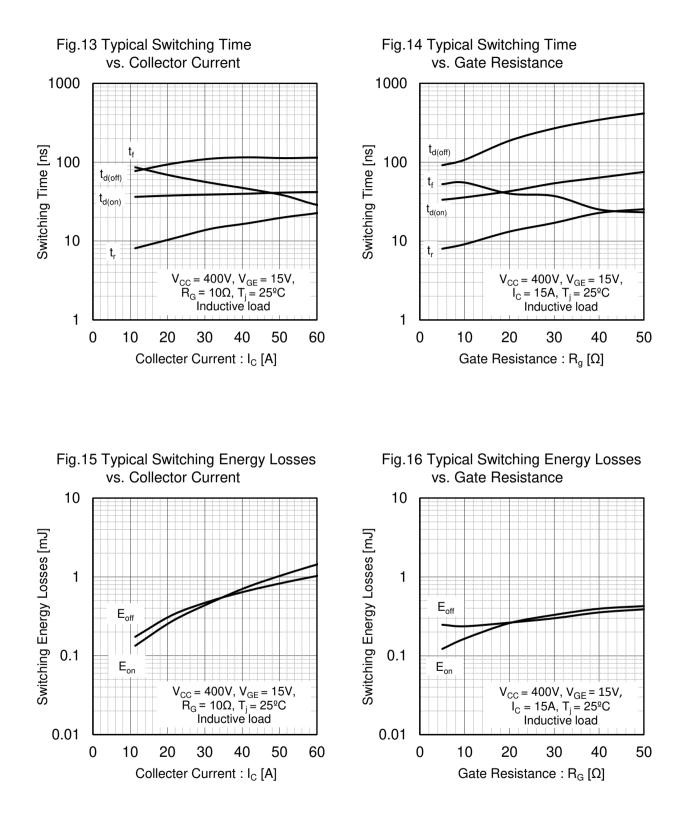


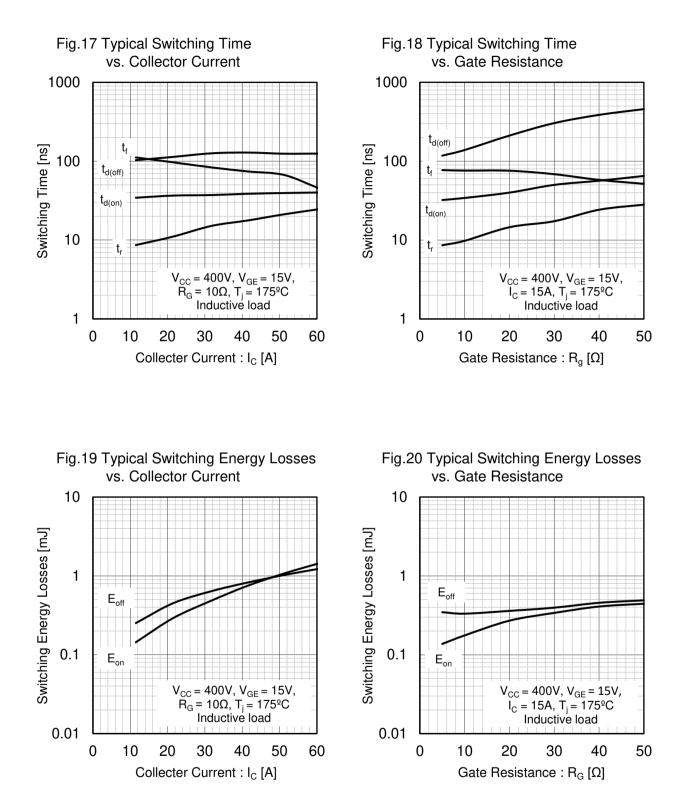


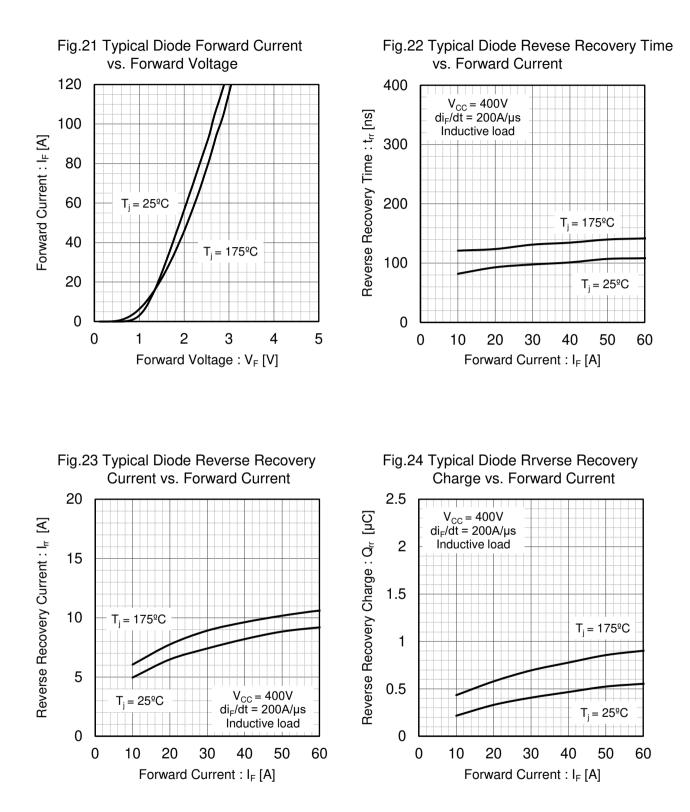












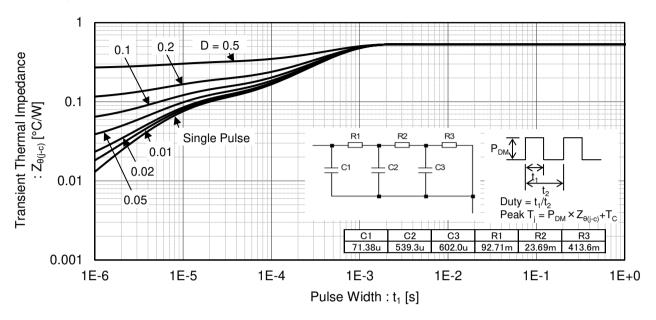
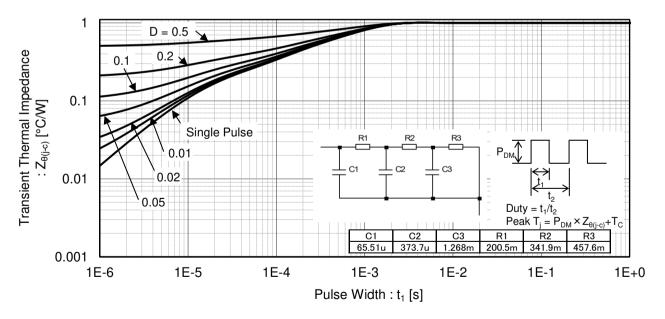


Fig.25 Typical IGBT Transient Thermal Impedance

Fig.26 Typical Diode Transient Thermal Impedance



#### Inductive Load Switching Circuit and Waveform

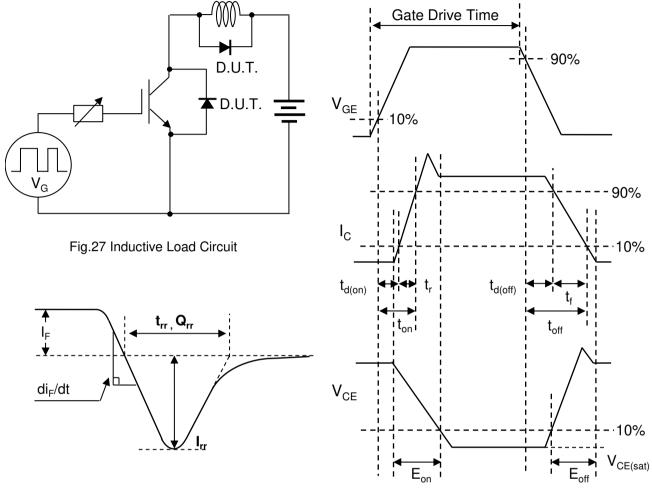


Fig.29 Diode Reverse Recovery Waveform

Fig.28 Inductive Load Waveform

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